

# DW\_ram\_2r\_w\_a\_dff

# Write-Port, Dual-Read-Port RAM (Flip-Flop-Based)

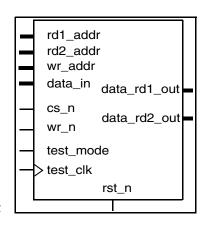
Version, STAR and Download Information: IP Directory

### **Features and Benefits**

- Parameterized word depth
- Parameterized data width
- Asynchronous static memory
- Parameterized reset implementation
- High testability using DFT Compiler

# **Description**

DW\_ram\_2r\_w\_a\_dff implements a parameterized, asynchronous, three-port static RAM.



#### Table 1-1 Pin Description

Pin Name	Width	Direction	Function
rst_n	1 bit	Input	Reset, active low
cs_n	1 bit	Input	Chip select, active low
wr_n	1 bit	Input	Write enable, active low
test_mode	1 bit	Input	Enables test_clk
test_clk	1 bit	Input	Test clock to capture data during test_mode
rd1_addr	ceil(log <sub>2</sub> [depth]) bit(s)	Input	Read1 address bus
rd2_addr	ceil(log <sub>2</sub> [depth]) bit(s)	Input	Read2 address bus
wr_addr	ceil(log <sub>2</sub> [depth]) bit(s)	Input	Write address bus
data_in	data_width bit(s)	Input	Input data bus
data_rd1_out	data_width bit(s)	Output	Output data bus for read1
data_rd2_out	data_width bit(s)	Output	Output data bus for read2

**Table 1-2** Parameter Description

Parameter	Values	Description
data_width	1 to 256	Width of data_in and data_out buses. Default = none
depth	2 to 256	Number of words in the memory array (address width). Default = none
rst_mode	0 or 1 Default = 1	Determines if the rst_n input is used.  0 = rst_n initializes the RAM  1 = rst_n is not connected

#### Table 1-3 Synthesis Implementations

Implementation Name	Function	License Feature Required
rtl <sup>a</sup>	Synthesis model	DesignWare

a. The implementation, "rtl," replaces the obsolete implementation, "str." Existing designs that specify the obsolete implementation ("str") will automatically have that implementation replaced by the new superseding implementation ("rtl") as will be noted by an information message (SYNDB-36) generated during DC compilation.

#### Table 1-4 Simulation Models

Model	Function	
DW06.DW_RAM_2R_W_A_DFF_CFG_SIM	VHDL simulation configuration	
dw/dw06/src/DW_ram_2r_w_a_dff_sim.vhd	VHDL simulation model source code	
dw/sim_ver/DW_ram_2r_w_a_dff.v	Verilog simulation model source code	

The write data enters the RAM through the data\_in input port, and is read out through either the data\_rd1\_out port or the data\_rd2\_out port. The RAM is constantly reading regardless of the state of cs\_n.

The rd1\_addr, rd2\_addr, and wr\_addr ports are used to address the *depth* words in memory. If rd1\_addr or rd2\_addr contains a value beyond the maximum depth, then that output port is driven LOW. For example, if rd1\_addr = 7 hex and depth = 6, then the data\_rd1\_out bus is driven LOW. If rd2\_addr is beyond the maximum depth, then data\_rd2\_out is driven low.

For wr\_addr beyond the maximum depth, nothing occurs and the data is lost. No warnings are given during simulations when an address beyond the scope of *depth* is used.



This component contains clock signals for internal flip-flops that are derived from the  $wr_n$  and  $test_clk$  ports. To keep hold times and internal clock skews to a minimum, you should consider instances of this component to be individual floorplanning elements.

## Chip Selection, Reading and Writing

The cs\_n input is the chip select, active low signal that enables data to be written to the RAM. The RAM is constantly reading, regardless of the state of cs\_n.

When cs\_n is *low* and there is a low-to-high transition of the write enable, wr\_n, data is written to the RAM.

Data is captured into the memory cell on the low-to-high transition of wr\_n. If rd1\_addr port or rd2\_addr port are the same value as wr\_addr, data\_in equals data\_rd1\_out or data\_rd2\_out, respectively, after the low-to-high transition of wr\_n.

When cs\_n is HIGH, writing to the RAM is disabled.

#### Reset

#### rst n

This signal is an active-low input that initializes the RAM to zeros if the rst\_mode parameter is set to 0, independent of the value of cs\_n. If the rst\_mode parameter is set to 1, rst\_n does not affect the RAM, and should be tied HIGH or LOW. In this case, synthesis optimizes the design, and does not use the rst\_n signal.

### Making the RAM Scannable

DW\_ram\_2r\_w\_a\_dff may be made scannable using DFT Compiler. Use the set\_test\_hold 1 test\_mode command before insert\_scan.

The test\_mode signal, when active high, selects the test\_clk port to control the capture of data into the RAM. The test\_mode signal may be tied LOW if a scannable design is not required. When test\_mode is tied LOW, synthesis optimizes the design, and does not connect the test\_mode and test\_clk signals to anything.



For scannable designs, the test\_mode signal should only be active during scan shifting (when scan enable is active). When test\_mode is active, all RAM addresses are written with the data\_in value at the rising edge of test\_clk. When test\_mode and scan enable are both active, the data currently in the RAM are shifted out for viewing the state of the RAM.

# **Application Notes**

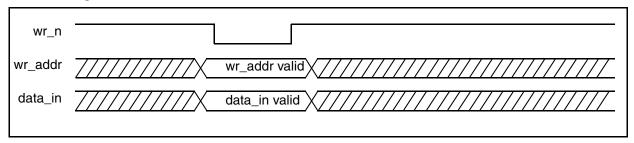
DW\_ram\_2r\_w\_a\_dff is intended to be used as a small scratch-pad memory or register file. Because DW\_ram\_2r\_w\_a\_dff is built from the cells within the ASIC cell library, it should be kept small to obtain an efficient implementation. If a larger memory is required, you should consider using a hard macro RAM from the ASIC library in use.

### **Timing Waveforms**

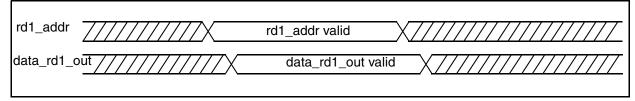
The figures in this section show timing diagrams for various conditions of DW\_ram\_2r\_w\_a\_dff.

Figure 1-1 Instantiated RAM Timing Waveforms

#### Write Timing, wr\_n controlled, rst\_mode = 1, cs\_n = 0, address valid before wr\_n transition to low



#### Read Port 1 Timing, address controlled, rst\_mode = 1, cs\_n = don't care



#### Read Port 2 Timing, address controlled, rst\_mode = 1, cs\_n = don't care

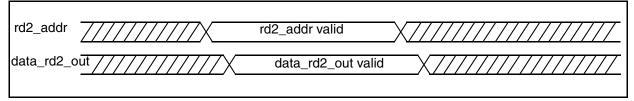
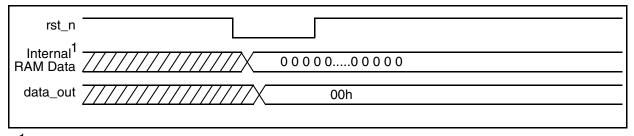


Figure 1-2 RAM Reset Timing Waveform

#### Asynchronous Reset, rst\_mode = 0, cs\_n = 0



<sup>&</sup>lt;sup>1</sup> Internal RAM Data is the array of memory bits; the memory is not available to users.

# **Related Topics**

- Memory Synchronous RAMs Listing
- DesignWare Building Block IP Documentation Overview

### **HDL Usage Through Component Instantiation - VHDL**

```
library IEEE, DWARE, DWARE;
use IEEE.std logic 1164.all;
use DWARE.DWpackages.all;
use DWARE.DW foundation comp.all;
entity DW_ram_2r_w_a_dff_inst is
  generic (inst data width : INTEGER := 8;
           inst depth
                           : INTEGER := 8;
           inst_rst_mode : INTEGER := 0 );
  port (inst_rst_n : in std_logic;
        inst_cs_n
                      : in std_logic;
                      : in std_logic;
        inst wr n
        inst test mode : in std logic;
        inst_test_clk : in std_logic;
       inst rd1 addr : in std logic vector(bit width(inst depth)-1 downto 0);
       inst rd2 addr : in std logic vector(bit width(inst depth)-1 downto 0);
        inst_wr_addr : in std_logic_vector(bit_width(inst_depth)-1 downto 0);
        inst_data_in : in std_logic_vector(inst_data_width-1 downto 0);
        data_rd1_out_inst : out std_logic_vector(inst_data_width-1 downto 0);
        data_rd2_out_inst : out std_logic_vector(inst_data_width-1 downto 0)
       );
end DW_ram_2r_w_a_dff_inst;
architecture inst of DW_ram_2r_w_a_dff_inst is
begin
  -- Instance of DW_ram_2r_w_a_dff
  U1 : DW ram 2r w a dff
    generic map (data width => inst data width,
                                                  depth => inst depth,
                 rst_mode => inst_rst_mode )
    port map (rst_n => inst_rst_n,
                                   cs_n => inst_cs_n,
                                                         wr_n => inst_wr_n,
              test mode => inst test mode,
                                             test clk => inst test clk,
              rd1_addr => inst_rd1_addr, rd2_addr => inst_rd2_addr,
                                         data in => inst data in,
              wr addr => inst wr addr,
              data_rd1_out => data_rd1_out_inst,
              data_rd2_out => data_rd2_out_inst );
end inst;
-- pragma translate_off
configuration DW ram 2r w a dff inst cfg inst of DW ram 2r w a dff inst is
  for inst
  end for; -- inst
end DW ram 2r w a dff inst cfg inst;
-- pragma translate_on
```

## **HDL Usage Through Component Instantiation - Verilog**

```
module DW_ram_2r_w_a_dff_inst(inst_rst_n, inst_cs_n, inst_wr_n,
          inst test mode, inst test clk, inst rd1 addr, inst rd2 addr,
          inst_wr_addr, inst_data_in, data_rd1_out_inst, data_rd2_out_inst );
  parameter data width = 8;
  parameter depth = 8;
  parameter rst_mode = 0;
  `define bit_width_depth 3 // ceil(log2(depth))
  input inst_rst_n;
  input inst_cs_n;
  input inst_wr_n;
  input inst_test_mode;
  input inst test clk;
  input [`bit_width_depth-1 : 0] inst_rd1_addr;
  input [`bit_width_depth-1 : 0] inst_rd2_addr;
  input [`bit_width_depth-1 : 0] inst_wr_addr;
  input [data_width-1 : 0] inst_data_in;
  output [data_width-1 : 0] data_rd1_out_inst;
  output [data_width-1 : 0] data_rd2_out_inst;
  // Instance of DW_ram_2r_w_a_dff
 DW_ram_2r_w_a_dff #(data_width,
                                    depth,
                                             rst_mode)
    U1 (.rst_n(inst_rst_n),
                            .cs_n(inst_cs_n),
                                                   .wr_n(inst_wr_n),
        .test_mode(inst_test_mode), .test_clk(inst_test_clk),
        .rd1_addr(inst_rd1_addr),
                                    .rd2_addr(inst_rd2_addr),
        .wr addr(inst wr addr),
                                 .data in(inst data in),
        .data_rd1_out(data_rd1_out_inst),
        .data_rd2_out(data_rd2_out_inst) );
```

endmodule

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